

TLV271

Single-Channel, Rail-to-Rail Output, 3 MHz BW Operational Amplifier

The TLV271 operational amplifier provides rail-to-rail output operation. The output can swing within 320 mV to the positive rail and 50 mV to the negative rail. This rail-to-rail operation enables the user to make optimal use of the entire supply voltage range while taking advantage of 3 MHz bandwidth. The TLV271 can operate on supply voltage as low as 2.7 V over the temperature range of -40°C to 105°C . The high bandwidth provides a slew rate of $2.4\text{ V}/\mu\text{s}$ while only consuming $550\text{ }\mu\text{A}$ of quiescent current. Likewise the TLV271 can run on a supply voltage as high as 16 V making it ideal for a broad range of battery-operated applications. Since this is a CMOS device it has high input impedance and low bias currents making it ideal for interfacing to a wide variety of signal sensors. In addition it comes in a small TSOP-5 package with two pinout styles allowing for use in high-density PCB's.

Features

- Rail-To-Rail Output
- Wide Bandwidth: 3 MHz
- High Slew Rate: $2.4\text{ V}/\mu\text{s}$
- Wide Power-Supply Range: 2.7 V to 16 V
- Low Supply Current: $550\text{ }\mu\text{A}$
- Low Input Bias Current: 1 pA
- Wide Temperature Range: -40°C to 105°C
- Small Package: 5 Pin TSOP-5 (same as SOT23-5)
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

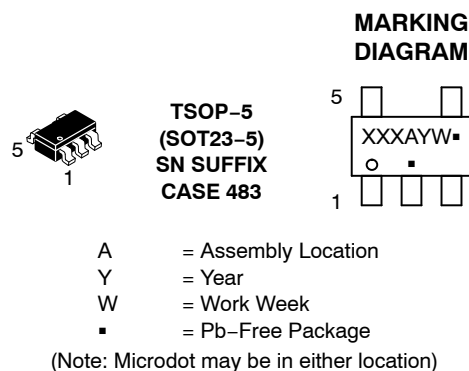
Applications

- Notebook Computers
- Portable Instruments

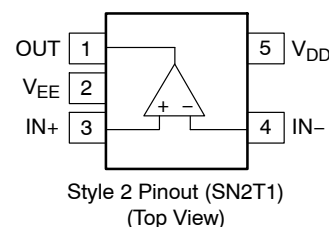
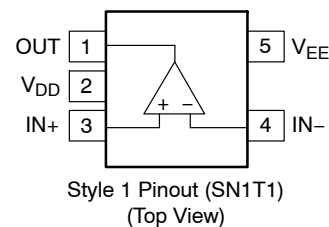


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PIN CONNECTIONS



ORDERING INFORMATION

Device	Package	Shipping [†]
TLV271SN1T1G (Style 1 Pinout)	TSOP-5 (Pb-Free)	3000 / Tape & Reel
TLV271SN2T1G (Style 2 Pinout)	TSOP-5 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Symbol	Rating	Value	Unit
V_{DD}	Supply Voltage (Note 1)	16.5	V
V_{ID}	Input Differential Voltage (Note 2)	$\pm$ Supply Voltage	V
V_I	Input Common Mode Voltage Range (Note 1)	$-0.2\text{ V to } (V_{DD} + 0.2\text{ V})$	V
I_I	Maximum Input Current	± 10	mA
I_O	Output Current Range	± 100	mA
	Continuous Total Power Dissipation (Note 1)	200	mW
T_J	Maximum Junction Temperature	150	$^{\circ}\text{C}$
θ_{JA}	Thermal Resistance	333	$^{\circ}\text{C/W}$
T_{stg}	Operating Temperature Range (free-air)	-40 to 105	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-65 to 150	$^{\circ}\text{C}$
	Mounting Temperature (Infrared or Convection – 20 sec)	260	$^{\circ}\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- Continuous short-circuit operation to ground at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C . Output currents in excess of 45 mA over long term may adversely affect reliability. Shorting output to either V_+ or V_- will adversely affect reliability.
- ESD data available upon request.

DC ELECTRICAL CHARACTERISTICS ($V_{DD} = 2.7\text{V}, 3.3\text{V}, 5\text{V} \text{ \& } \pm 5\text{ V}$ (Note 3), $T_A = 25^{\circ}\text{C}$, $R_L \geq 10\text{ k}\Omega$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input Offset Voltage	V_{IO}	$V_{IC} = V_{DD}/2$, $V_O = V_{DD}/2$, $R_L = 10\text{ k}\Omega$, $R_S = 50\text{ }\Omega$		0.5	5	mV
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$			7	
Offset Voltage Drift	ICV_{OS}	$V_{IC} = V_{DD}/2$, $V_O = V_{DD}/2$, $R_L = 10\text{ k}\Omega$, $R_S = 50\text{ }\Omega$		2		$\mu\text{V}/^{\circ}\text{C}$
Common Mode Rejection Ratio	CMRR	$0\text{ V} \leq V_{IC} \leq V_{DD} - 1.35\text{ V}$, $R_S = 50\text{ }\Omega$	$V_{DD} = 2.7\text{ V}$	58	70	dB
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		55		
		$0\text{ V} \leq V_{IC} \leq V_{DD} - 1.35\text{ V}$, $R_S = 50\text{ }\Omega$	$V_{DD} = 5\text{ V}$	65	130	
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		62		
		$0\text{ V} \leq V_{IC} \leq V_{DD} - 1.35\text{ V}$, $R_S = 50\text{ }\Omega$	$V_{DD} = \pm 5\text{ V}$	69	140	
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		66		
Power Supply Rejection Ratio	PSRR	$V_{DD} = 2.7\text{ V to } 16\text{ V}$, $V_{IC} = V_{DD}/2$, No Load	70	135		dB
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$	65			
Large Signal Voltage Gain	A_{VD}	$V_{O(pp)} = V_{DD}/2$, $R_L = 10\text{ k}\Omega$	$V_{DD} = 2.7\text{ V}$	97	106	dB
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		76		
		$V_{O(pp)} = V_{DD}/2$, $R_L = 10\text{ k}\Omega$	$V_{DD} = 3.3\text{ V}$	97	123	
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		76		
		$V_{O(pp)} = V_{DD}/2$, $R_L = 10\text{ k}\Omega$	$V_{DD} = 5\text{ V}$	100	127	
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		86		
		$V_{O(pp)} = V_{DD}/2$, $R_L = 10\text{ k}\Omega$	$V_{DD} = \pm 5\text{ V}$	100	130	
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		90		
Input Bias Current	I_B	$V_{DD} = 5\text{ V}$, $V_{IC} = V_{DD}/2$, $V_O = V_{DD}/2$, $R_S = 50\text{ }\Omega$	$T_A = 25^{\circ}\text{C}$	45	150	pA
			$T_A = 105^{\circ}\text{C}$		1000	

3. $V_{DD} = \pm 5\text{ V}$ is shorthand for $V_{DD} = +5\text{ V}$ and $V_{EE} = -5\text{ V}$.

DC ELECTRICAL CHARACTERISTICS ($V_{DD} = 2.7V, 3.3V, 5V$ & $\pm 5V$ (Note 3), $T_A = 25^\circ C$, $R_L \geq 10\text{ k}\Omega$ unless otherwise noted)

Parameter	Symbol	Conditions		Min	Typ	Max	Unit
Input Offset Current	I_{IO}	$V_{DD} = 5V$, $V_{IC} = V_{DD}/2$, $V_O = V_{DD}/2$, $R_S = 50\ \Omega$	$T_A = 25^\circ C$		45	150	pA
			$T_A = 105^\circ C$			1000	
Differential Input Resistance	$r_{i(d)}$				1000		G Ω
Common-mode Input Capacitance	C_{IC}	$f = 21\text{ kHz}$			8		pF
Output Swing (High-level)	V_{OH}	$V_{IC} = V_{DD}/2$, $I_{OH} = -1\text{ mA}$	$V_{DD} = 2.7V$	2.55	2.58		V
		$T_A = -40^\circ C$ to $+105^\circ C$		2.48			
		$V_{IC} = V_{DD}/2$, $I_{OH} = -1\text{ mA}$	$V_{DD} = 3.3V$	3.15	3.21		
		$T_A = -40^\circ C$ to $+105^\circ C$		3.00			
		$V_{IC} = V_{DD}/2$, $I_{OH} = -1\text{ mA}$	$V_{DD} = 5V$	4.8	4.93		
		$T_A = -40^\circ C$ to $+105^\circ C$		4.75			
		$V_{IC} = V_{DD}/2$, $I_{OH} = -1\text{ mA}$	$V_{DD} = \pm 5V$	4.92	4.96		
		$T_A = -40^\circ C$ to $+105^\circ C$		4.9			
		$V_{IC} = V_{DD}/2$, $I_{OH} = -5\text{ mA}$	$V_{DD} = 2.7V$	1.9	2.1		V
		$T_A = -40^\circ C$ to $+105^\circ C$		1.5			
		$V_{IC} = V_{DD}/2$, $I_{OH} = -5\text{ mA}$	$V_{DD} = 3.3V$	2.5	2.89		
		$T_A = -40^\circ C$ to $+105^\circ C$		2.1			
		$V_{IC} = V_{DD}/2$, $I_{OH} = -5\text{ mA}$	$V_{DD} = 5V$	4.5	4.68		
		$T_A = -40^\circ C$ to $+105^\circ C$		4.35			
		$V_{IC} = V_{DD}/2$, $I_{OH} = -5\text{ mA}$	$V_{DD} = \pm 5V$	4.7	4.78		
		$T_A = -40^\circ C$ to $+105^\circ C$		4.65			
Output Swing (Low-level)	V_{OL}	$V_{IC} = V_{DD}/2$, $I_{OL} = -1\text{ mA}$	$V_{DD} = 2.7V$		0.1	0.15	V
		$T_A = -40^\circ C$ to $+105^\circ C$				0.22	
		$V_{IC} = V_{DD}/2$, $I_{OL} = -1\text{ mA}$	$V_{DD} = 3.3V$		0.03	0.15	
		$T_A = -40^\circ C$ to $+105^\circ C$				0.22	
		$V_{IC} = V_{DD}/2$, $I_{OL} = -1\text{ mA}$	$V_{DD} = 5V$		0.03	0.1	
		$T_A = -40^\circ C$ to $+105^\circ C$				0.15	
		$V_{IC} = V_{DD}/2$, $I_{OL} = -1\text{ mA}$	$V_{DD} = \pm 5V$		0.05	0.08	
		$T_A = -40^\circ C$ to $+105^\circ C$				0.1	
		$V_{IC} = V_{DD}/2$, $I_{OL} = -5\text{ mA}$	$V_{DD} = 2.7V$		0.5	0.7	V
		$T_A = -40^\circ C$ to $+105^\circ C$				1.1	
		$V_{IC} = V_{DD}/2$, $I_{OL} = -5\text{ mA}$	$V_{DD} = 3.3V$		0.13	0.7	
		$T_A = -40^\circ C$ to $+105^\circ C$				1.1	
		$V_{IC} = V_{DD}/2$, $I_{OL} = -5\text{ mA}$	$V_{DD} = 5V$		0.13	0.4	
		$T_A = -40^\circ C$ to $+105^\circ C$				0.5	
		$V_{IC} = V_{DD}/2$, $I_{OL} = -5\text{ mA}$	$V_{DD} = \pm 5V$		0.16	0.3	
		$T_A = -40^\circ C$ to $+105^\circ C$				0.35	

3. $V_{DD} = \pm 5V$ is shorthand for $V_{DD} = +5V$ and $V_{EE} = -5V$.

TLV271

DC ELECTRICAL CHARACTERISTICS ($V_{DD} = 2.7V, 3.3V, 5V$ & $\pm 5V$ (Note 3), $T_A = 25^\circ C$, $R_L \geq 10\text{ k}\Omega$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Current	I_O	$V_O = 0.5\text{ V from rail, } V_{DD} = 2.7\text{ V}$	Positive rail	4.0		mA
			Negative rail	5.0		
		$V_O = 0.5\text{ V from rail, } V_{DD} = 5\text{ V}$	Positive rail	7.0		
			Negative rail	8.0		
		$V_O = 0.5\text{ V from rail, } V_{DD} = 10\text{ V}$	Positive rail	13		
			Negative rail	12		
Power Supply Quiescent Current	I_{DD}	$V_O = V_{DD}/2$	$V_{DD} = 2.7\text{ V}$	380	560	μA
			$V_{DD} = 3.3\text{ V}$	385	620	
			$V_{DD} = 5\text{ V}$	390	660	
			$V_{DD} = 10\text{ V}$	400	800	
		$T_A = -40^\circ C \text{ to } +105^\circ C$			1000	

3. $V_{DD} = \pm 5\text{ V}$ is shorthand for $V_{DD} = +5\text{ V}$ and $V_{EE} = -5\text{ V}$.

AC ELECTRICAL CHARACTERISTICS ($V_{DD} = 2.7\text{ V}, 5\text{ V},$ & $\pm 5\text{ V}$ (Note 4), $T_A = 25^\circ C$, and $R_L \geq 10\text{ k}\Omega$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Unity Gain Bandwidth	UGBW	$R_L = 2\text{ k}\Omega, C_L = 10\text{ pF}$	$V_{DD} = 2.7\text{ V}$	3.2		MHz
			$V_{DD} = 5\text{ V to } 10\text{ V}$	3.5		
Slew Rate at Unity Gain	SR	$V_{O(pp)} = V_{DD}/2, R_L = 10\text{ k}\Omega, C_L = 50\text{ pF}$ $T_A = -40^\circ C \text{ to } +105^\circ C$	$V_{DD} = 2.7\text{ V}$	1.35	2.1	$V/\mu S$
				1		
		$V_{O(pp)} = V_{DD}/2, R_L = 10\text{ k}\Omega, C_L = 50\text{ pF}$ $T_A = -40^\circ C \text{ to } +105^\circ C$	$V_{DD} = 5\text{ V}$	1.45	2.3	
				1.2		
		$V_{O(pp)} = V_{DD}/2, R_L = 10\text{ k}\Omega, C_L = 50\text{ pF}$ $T_A = -40^\circ C \text{ to } +105^\circ C$	$V_{DD} = \pm 5\text{ V}$	1.8	2.6	
				1.3		
Phase Margin	θ_m	$R_L = 2\text{ k}\Omega, C_L = 10\text{ pF}$		45		$^\circ$
Gain Margin		$R_L = 2\text{ k}\Omega, C_L = 10\text{ pF}$		14		dB
Settling Time to 0.1%	t_S	$V\text{-step}(pp) = 1\text{ V}, AV = -1, R_L = 2\text{ k}\Omega, C_L = 10\text{ pF}$	$V_{DD} = 2.7\text{ V}$	2.9		μS
		$V\text{-step}(pp) = 1\text{ V}, AV = -1, R_L = 2\text{ k}\Omega, C_L = 47\text{ pF}$	$V_{DD} = 5\text{ V}, \pm 5\text{ V}$	2.0		
Total Harmonic Distortion plus Noise	THD+N	$V_{DD} = 2.7\text{ V}, V_{O(pp)} = V_{DD}/2, R_L = 2\text{ k}\Omega, f = 10\text{ kHz}$	$AV = 1$	0.004		%
			$AV = 10$	0.04		
			$AV = 100$	0.3		
		$V_{DD} = 5\text{ V}, \pm 5\text{ V}, V_{O(pp)} = V_{DD}/2, R_L = 2\text{ k}\Omega, f = 10\text{ kHz}$	$AV = 1$	0.004		
			$AV = 10$	0.04		
			$AV = 100$	0.03		
Input-Referred Voltage Noise	e_n	$f = 1\text{ kHz}$		30		$nV/\sqrt{Hz}$
		$f = 10\text{ kHz}$		20		
Input-Referred Current Noise	i_n	$f = 1\text{ kHz}$		0.6		$fA/\sqrt{Hz}$

4. $V_{DD} = \pm 5\text{ V}$ is shorthand for $V_{DD} = +5\text{ V}$ and $V_{EE} = -5\text{ V}$.

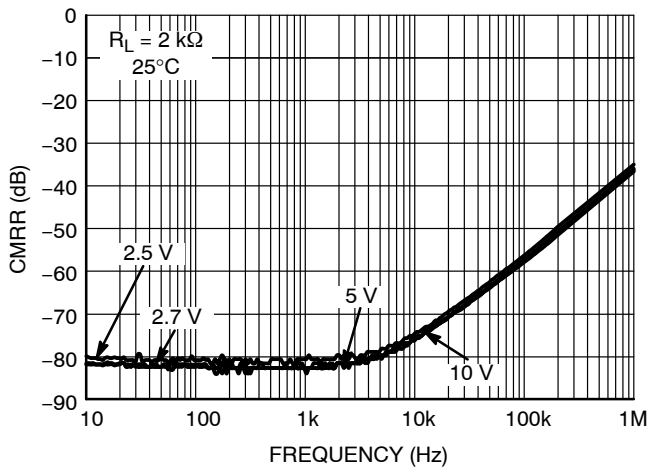


Figure 1. CMRR vs. Frequency

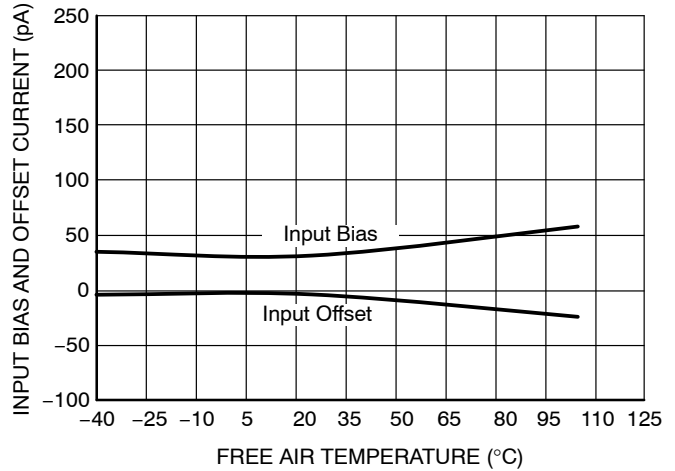


Figure 2. Input Bias and Offset Current vs. Temperature

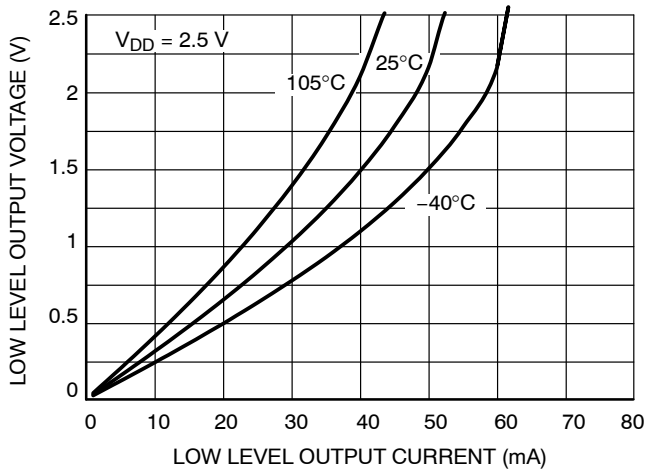


Figure 3. 2.5 V V_{OL} vs. I_{out}

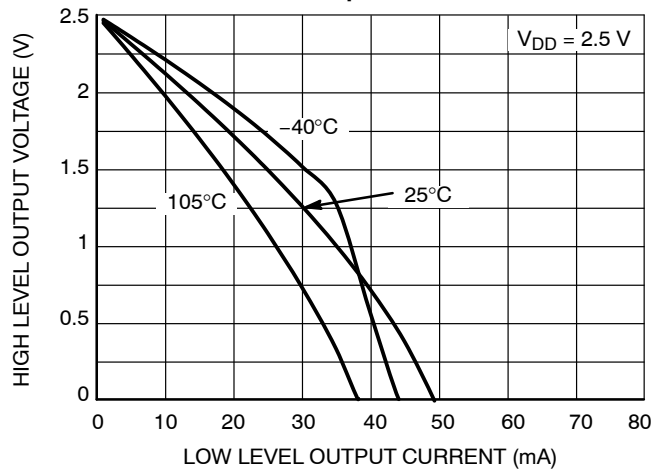


Figure 4. 2.5 V V_{OH} vs. I_{out}

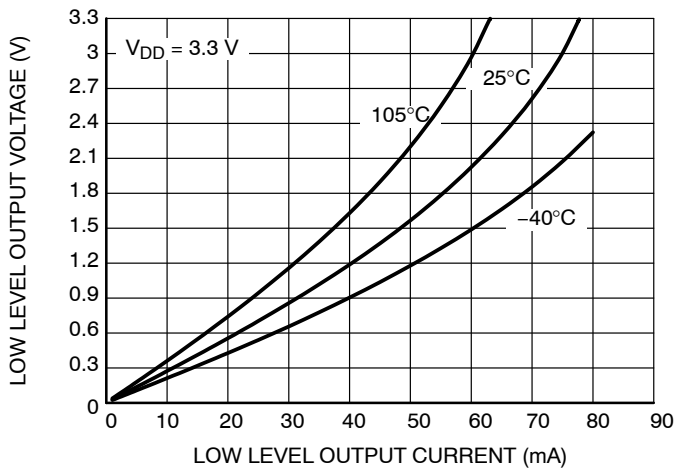


Figure 5. 3.3 V V_{OL} vs. I_{out}

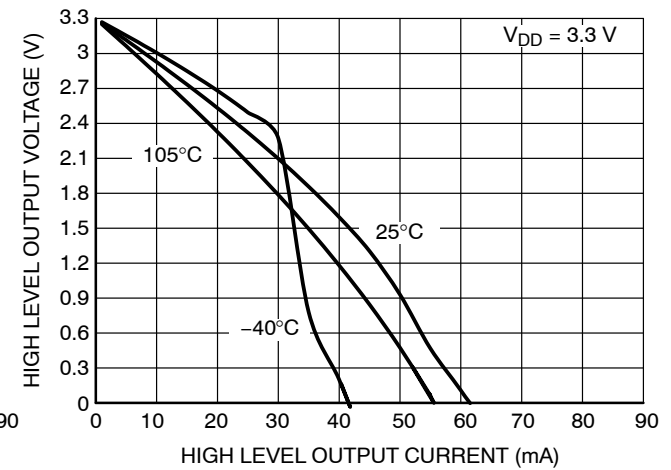


Figure 6. 3.3 V V_{OH} vs. I_{out}

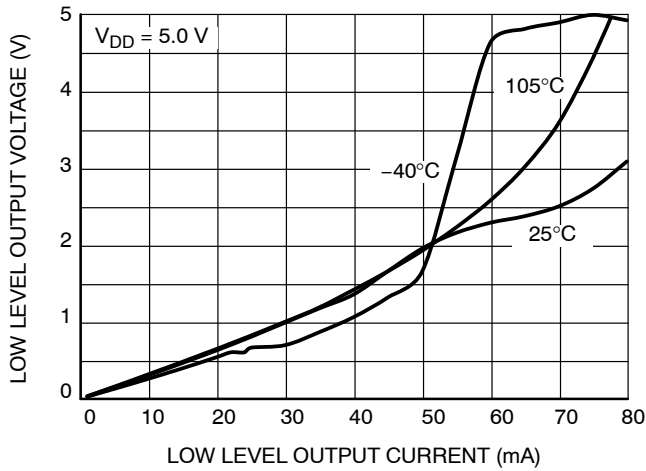


Figure 7. V_{OL} vs. I_{out}

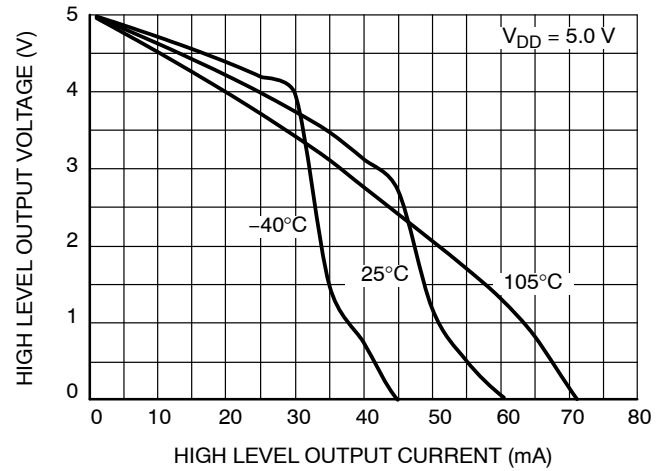


Figure 8. V_{OH} vs. I_{out}

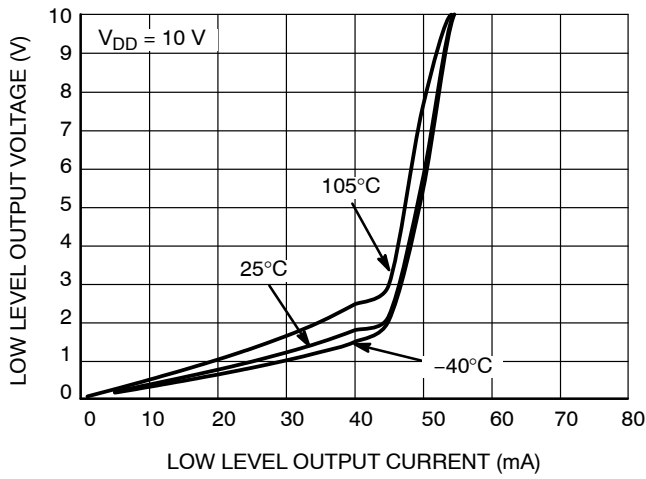


Figure 9. 10 V V_{OL} vs. I_{out}

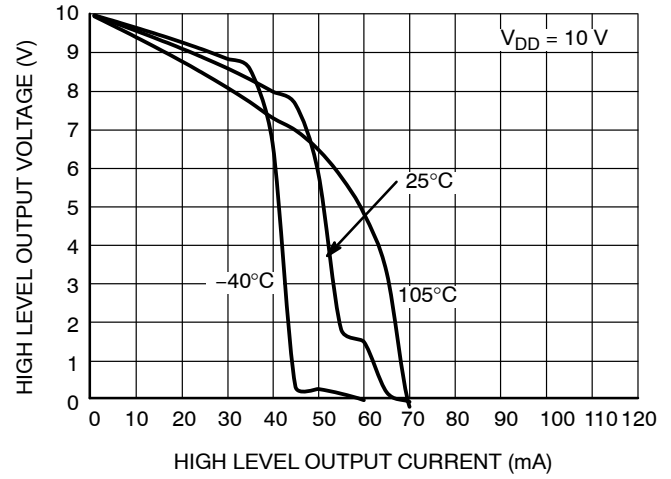


Figure 10. 10 V V_{OH} vs. I_{out}

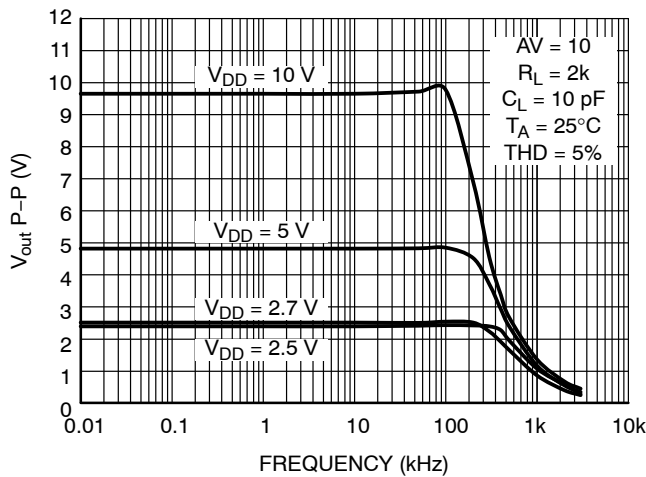


Figure 11. Peak-to-Peak Output vs. Supply vs. Frequency

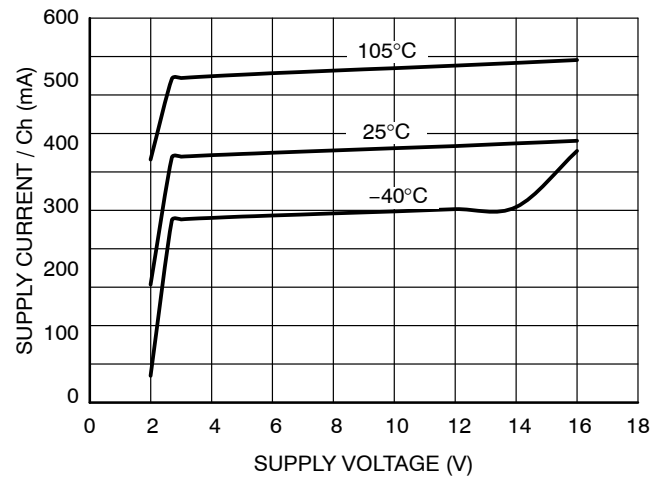


Figure 12. Supply Current vs. Supply Voltage

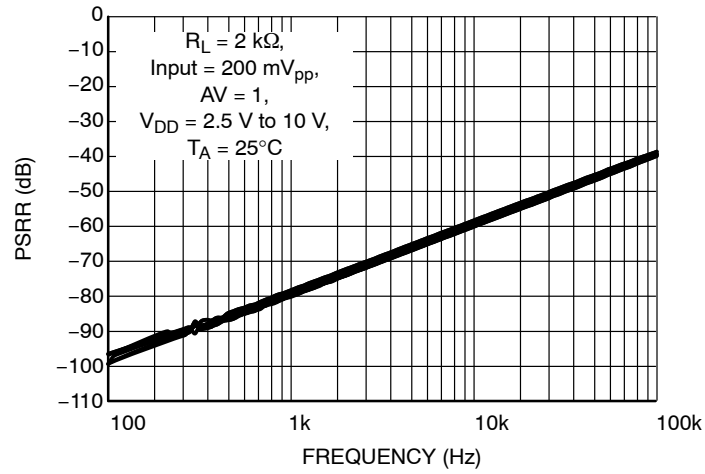


Figure 13. PSRR vs. Frequency

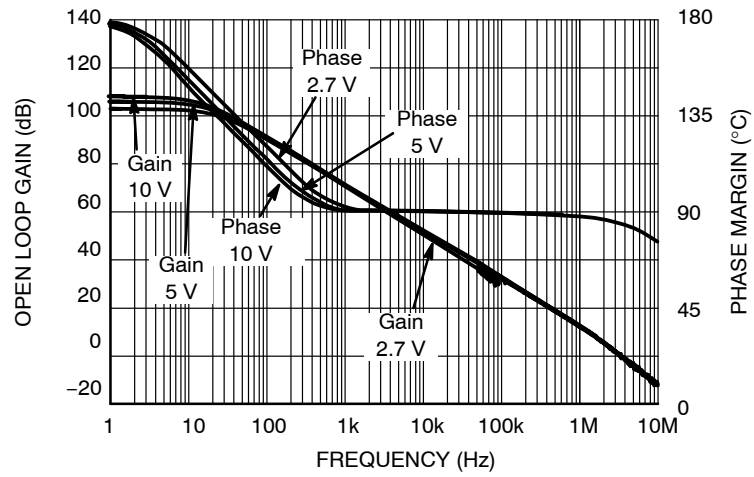


Figure 14. Open Loop Gain and Phase vs. Frequency

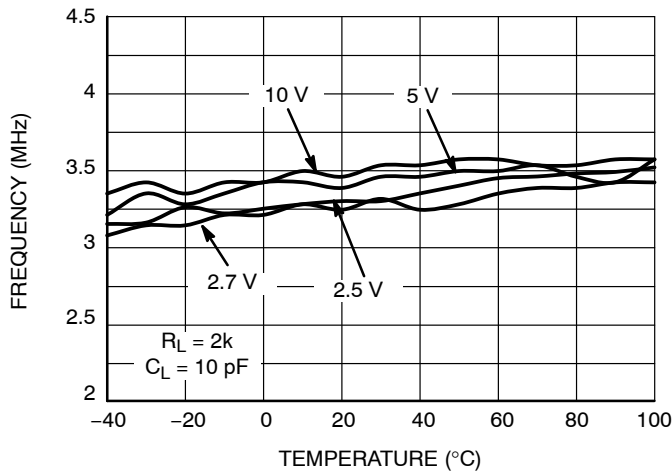


Figure 15. Gain Bandwidth Product vs. Temperature

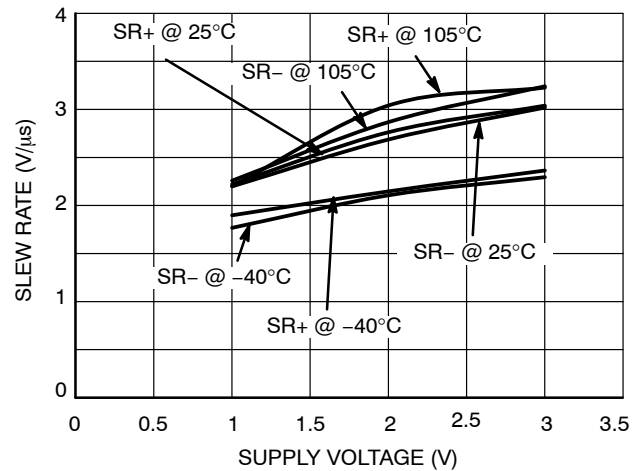


Figure 16. Slew Rate vs. Supply Voltage

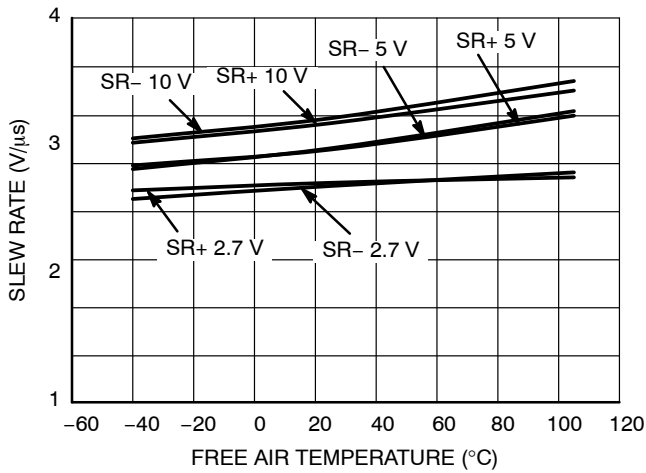


Figure 17. Slew Rate vs. Temperature

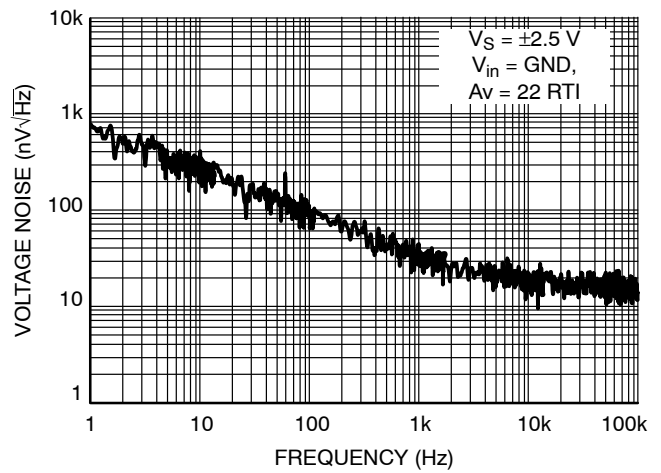


Figure 18. Voltage Noise vs. Frequency

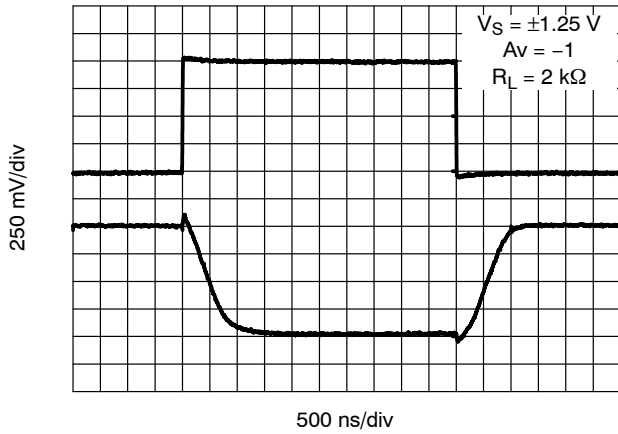


Figure 19. 2.5 V Inverting Large Signal Pulse Response

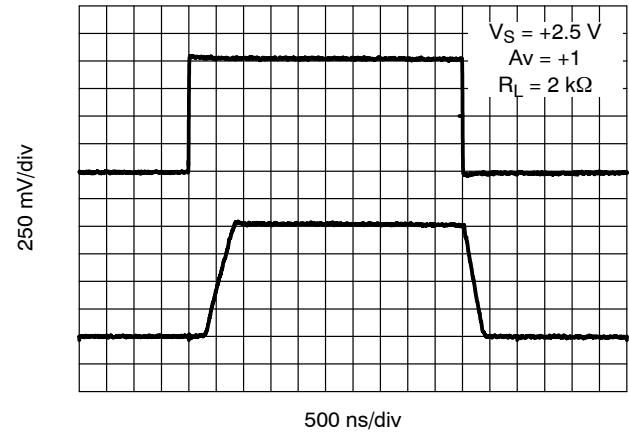


Figure 20. 2.5 V Non-Inverting Large Signal Pulse Response

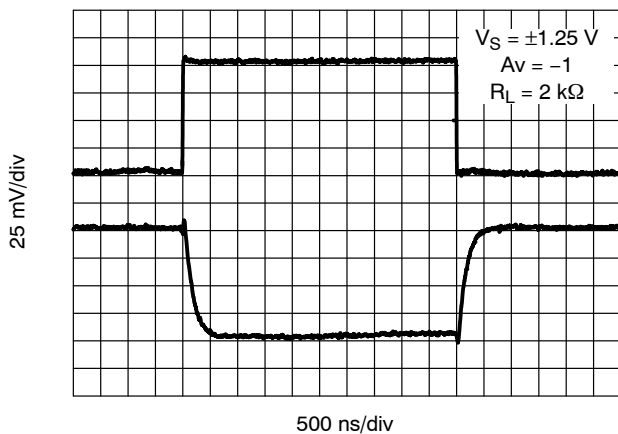


Figure 21. 2.5 V Inverting Small Signal Pulse Response

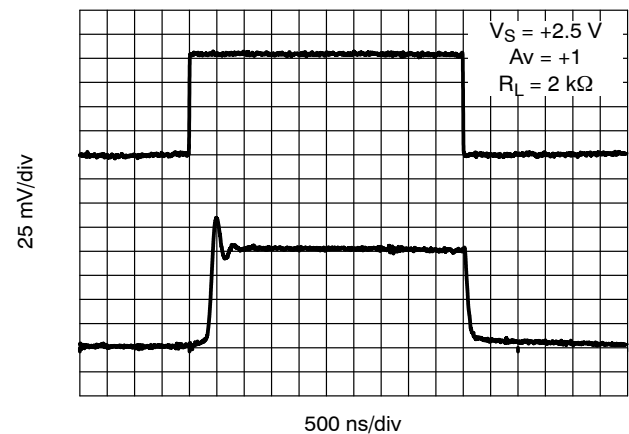


Figure 22. 2.5 V Non-Inverting Small Signal Pulse Response

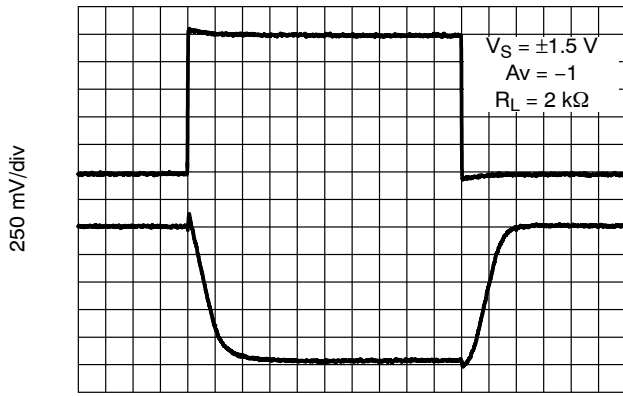


Figure 23. 3 V Inverting Large Signal Pulse Response

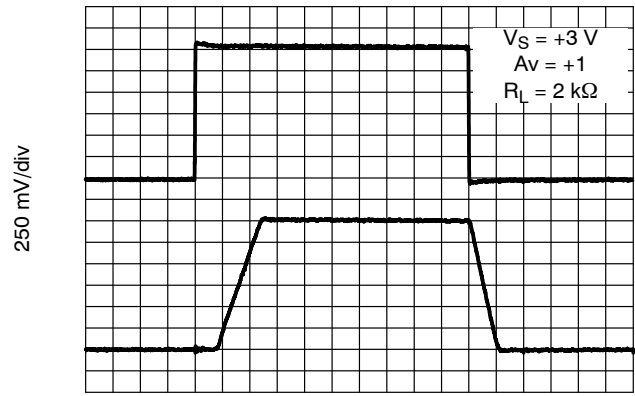


Figure 24. 3 V Non-Inverting Large Signal Pulse Response

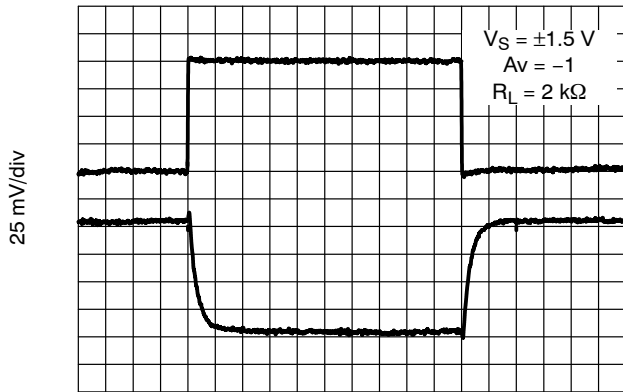


Figure 25. 3 V Inverting Small Signal Pulse Response

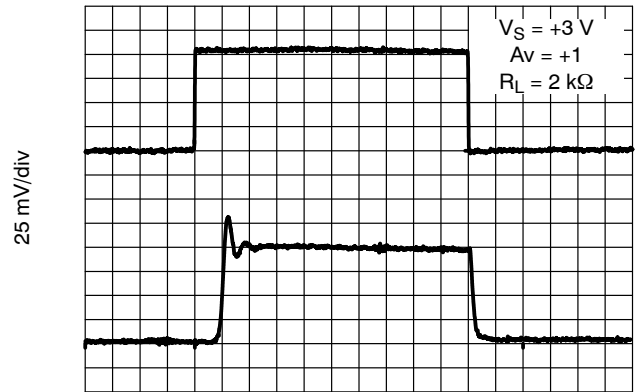


Figure 26. 3 V Non-Inverting Small Signal Pulse Response

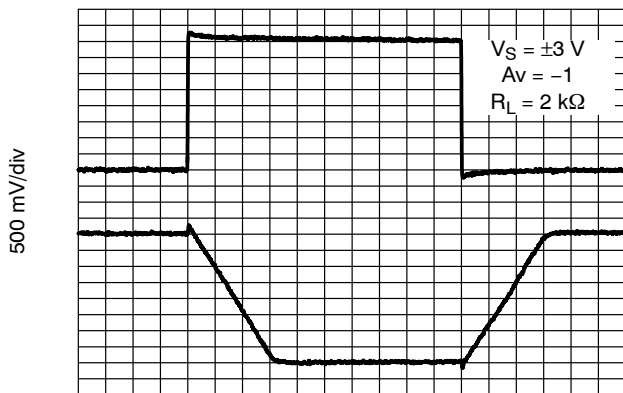


Figure 27. 6 V Inverting Large Signal Pulse Response

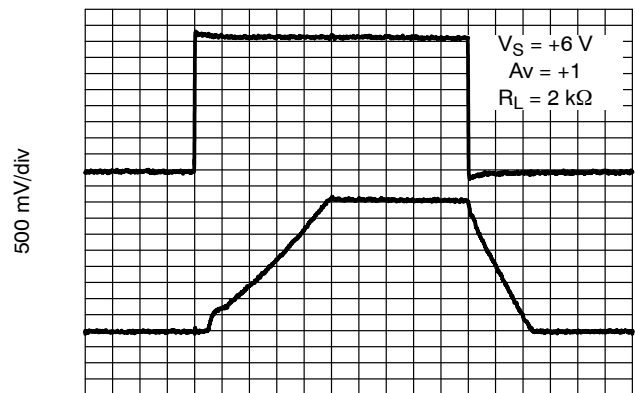


Figure 28. 6 V Non-Inverting Large Signal Pulse Response

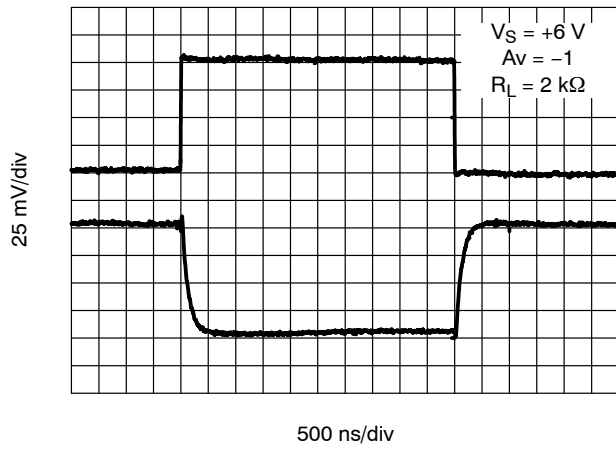


Figure 29. 6 V Inverting Small Signal Pulse Response

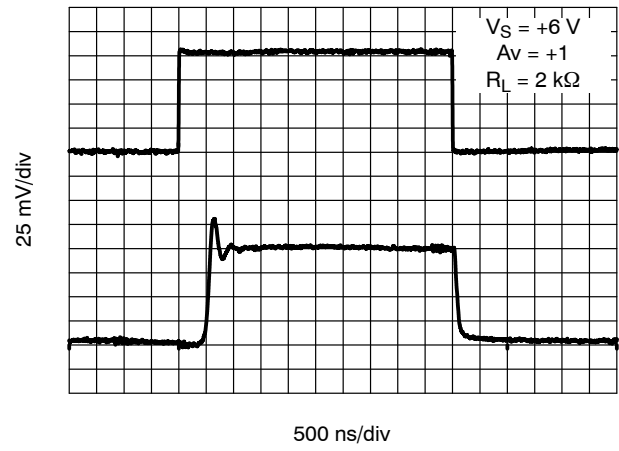


Figure 30. 6 V Non-Inverting Small Signal Pulse Response

APPLICATIONS

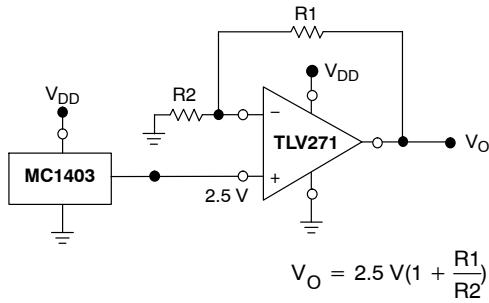


Figure 31. Voltage Reference

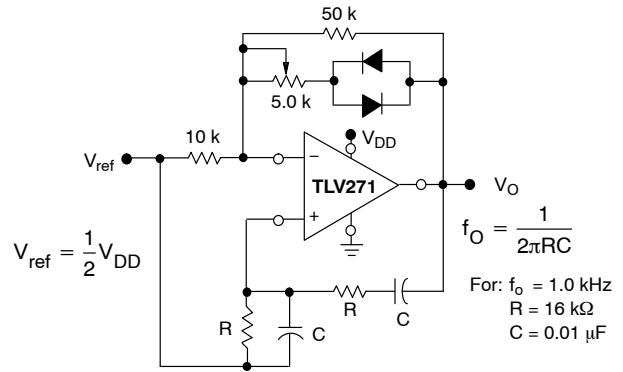


Figure 32. Wien Bridge Oscillator

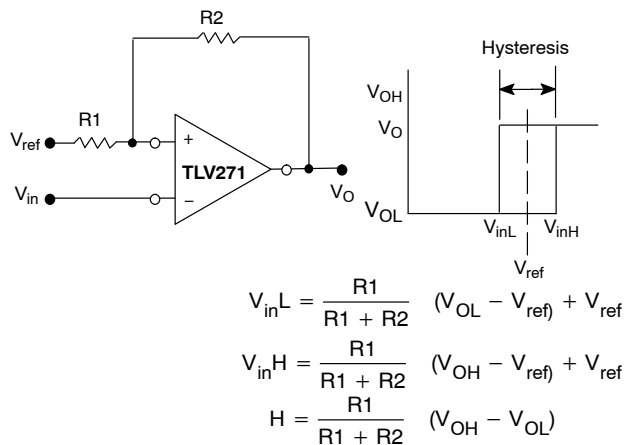
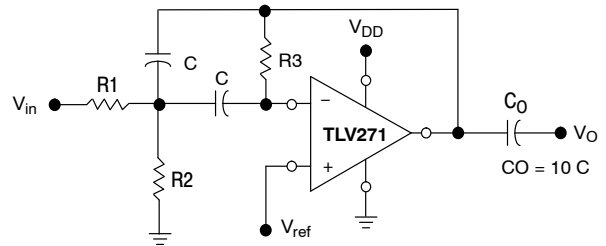


Figure 33. Comparator with Hysteresis



Given: f_O = center frequency
 $A(f_O)$ = gain at center frequency

Choose value f_O, C

Then: $R3 = \frac{Q}{\pi f_O C}$

$$R1 = \frac{R3}{2 A(f_O)}$$

$$R2 = \frac{R1 R3}{4Q^2 R1 - R3}$$

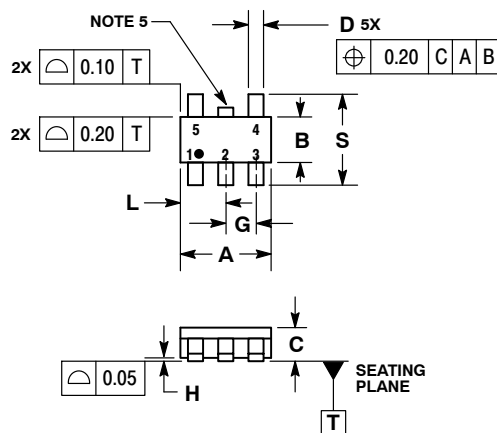
For less than 10% error from operational amplifier,
 $((Q_O f_O)/BW) < 0.1$ where f_O and BW are expressed in Hz.
 If source impedance varies, filter may be preceded with
 voltage follower buffer to stabilize filter parameters.

Figure 34. Multiple Feedback Bandpass Filter

TLV271

PACKAGE DIMENSIONS

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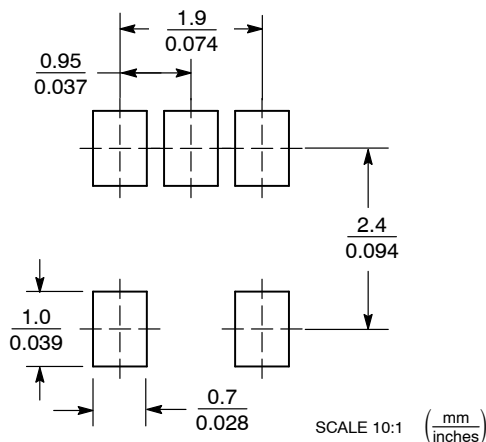


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.
5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

MILLIMETERS		
DIM	MIN	MAX
A	3.00 BSC	
B	1.50 BSC	
C	0.90	1.10
D	0.25	0.50
G	0.95 BSC	
H	0.01	0.10
J	0.10	0.26
K	0.20	0.60
L	1.25	1.55
M	0°	10°
S	2.50	3.00

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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